



### **New Product**

# MMM.100X.C **Dual P-Channel 20-V (D-S) MOSFET**

V <sub>DS</sub> (V)	SUMMARY r <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A)
COMIT	0.015 at V <sub>GS</sub> = - 4.5 V	- 9.4
- 20	0.019 at V <sub>GS</sub> = - 2.5 V	- 8.4
I.COM	0.024 at V <sub>GS</sub> = - 1.8 V	- 7.5

#### **FEATURES**

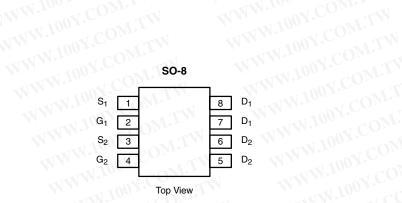
- TrenchFET® Power MOSFET
- Advanced High Cell Density Process



#### RoHS' COMPLIANT

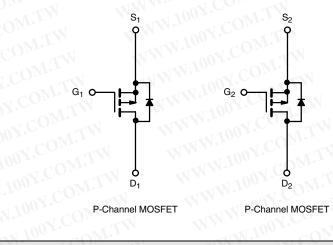
#### **APPLICATIONS**

Load Switching



Ordering Information: Si4913DY-T1

Si4913DY-T1-E3 (Lead (Pb)-free)



Parameter	WWW.	Symbol	10 sec	Steady State	Unit
Drain-Source Voltage		$V_{DS}$	- 20 ± 8		OX-COM
Gate-Source Voltage		$V_{GS}$			
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 25 °C	I <sub>D</sub> CC	- 9.4	- 7.1	001.
	T <sub>A</sub> = 70 °C		- 7.5	- 5.7	TOUX CO
Pulsed Drain Current		I <sub>DM</sub>	- 30		Jun A
Continuous Source Current (Diode Conduction) <sup>a</sup>		l <sub>S</sub>	- 1.7	- 0.9	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 25 °C	P <sub>D</sub>	2.0	1.1	W.100
	T <sub>A</sub> = 70 °C		1.3	0.7	VV
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C

operating caretain and otherspire in polarity parties		37 Sig			W. 100		
THERMAL DECISTANCE DAT	CONTRA	WWW.10	OY.COM.		MW 10		
THERMAL RESISTANCE RAT Parameter	INGS	Symbol	Typical	Maximum	Unit		
Maximum Junction-to-Ambient <sup>a</sup>	t ≤ 10 sec	R <sub>thJA</sub>	45	62.5	TININ		
	Steady State		85	110	°C/W		
Maximum Junction-to-Foot (Drain)	Steady State	R <sub>thJF</sub>	26	35			

#### Notes:

a. Surface Mounted on 1" x 1" FR4 Board.

\* Pb containing terminations are not RoHS compliant, exemptions may apply.

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# Vishay Siliconix

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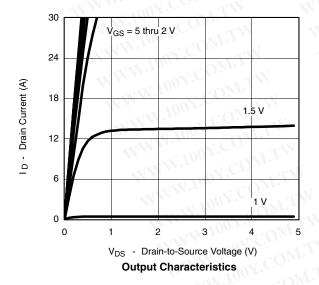
<b>SPECIFICATIONS</b> $T_J = 25^{\circ}$	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static	Oyllibor	rest conditions	CUMIN	136	WIGA	Oilit	
	V	$V_{DS} = V_{GS}, I_{D} = -500 \mu\text{A}$	- 0.40	- 1	- 1.0	V	
Gate Threshold Voltage	V <sub>GS(th)</sub>		- 0.40	TW			
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$	A COM	- CVN	± 100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}$	- c0!	1.1	-1		
		$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$	07.0	WT.M.	- 5	μΑ	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>DS</sub> = - 5 V, V <sub>GS</sub> = - 4.5 V	- 30	TV		Α	
Drain-Source On-State Resistance <sup>a</sup>	r <sub>DS(on)</sub>	V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 9.4 A	ov C	0.0125	0.015	Ω	
		$V_{GS} = -2.5 \text{ V}, I_D = -8.4 \text{ A}$	700 -	0.0155	0.019		
		$V_{GS} = -1.8 \text{ V}, I_D = -3.0 \text{ A}$	VI 100 X.	0.020	0.024		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 10 V, I <sub>D</sub> = - 9.4 A	100	40	TW	S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = - 1.7 A, V <sub>GS</sub> = 0 V	W. 1	- 0.7	- 1.2	V	
Dynamic <sup>b</sup>	With	Ing. COM.	MM.In.	COD	1. ×		
Total Gate Charge	$Q_g$	1100 T. ON. TW	_TXV.10	43	65	nC	
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -9.4 \text{ A}$	W	7.1	WILL		
Gate-Drain Charge	$Q_{gd}$	W.IO. COM.	NWW.	10.9	OB.		
Turn-On Delay Time	t <sub>d(on)</sub>	MAIN TOO TO COM!		32	50	xXI	
Rise Time	t <sub>r</sub>	$V_{DD}$ = 10 V, $R_L$ = 10 $\Omega$ $I_D \cong$ - 1 A, $V_{GEN}$ = - 4.5 V, $R_G$ = 6 $\Omega$		42	65	7	
Turn-Off Delay Time	t <sub>d(off)</sub>		MAN	350	525	ns	
Fall Time	t <sub>f</sub>	XWW.162 COM.	WW	160	240		
Source-Drain Reverse Recovery Time	, t <sub>rr</sub>	I <sub>F</sub> = - 1.7 A, di/dt = 100 A/μs	-11	127	200		

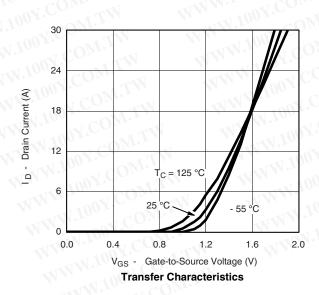
#### Notes:

- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### TYPICAL CHARACTERISTICS 25 °C unless noted

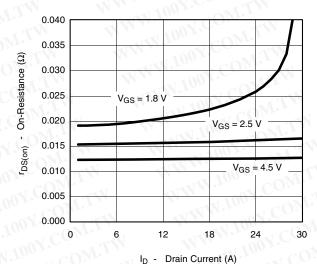




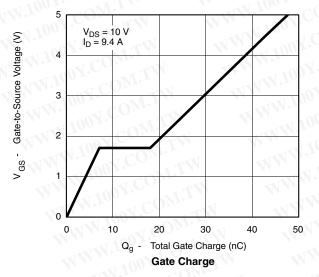
**Si4913DY** 

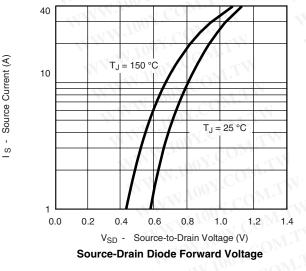
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On-Resistance vs. Drain Current

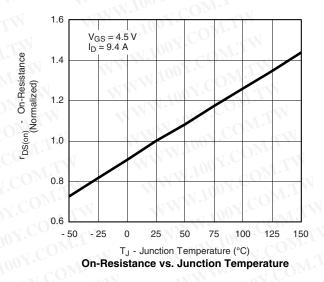


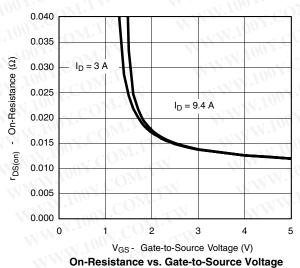


6000 5000 4000 4000 0 1000 C<sub>rss</sub> C<sub>oss</sub> 0 4 8 12 16 20

V<sub>DS</sub> - Drain-to-Source V oltage (V)

Capacitance





# **Si4913DY**

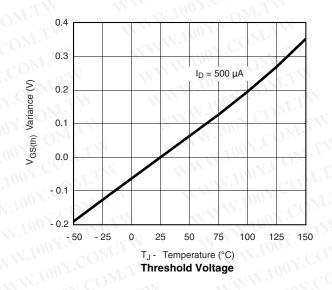
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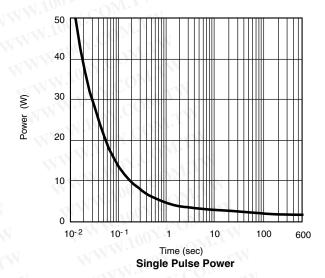
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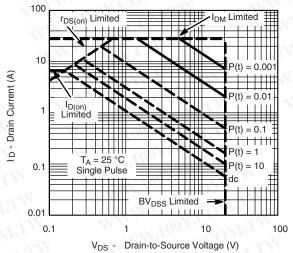
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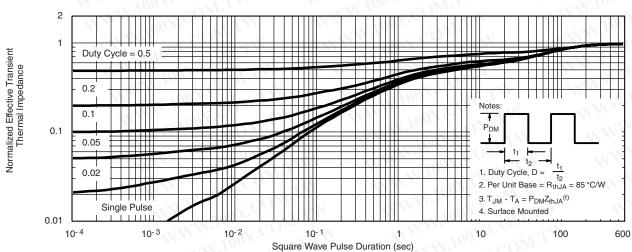
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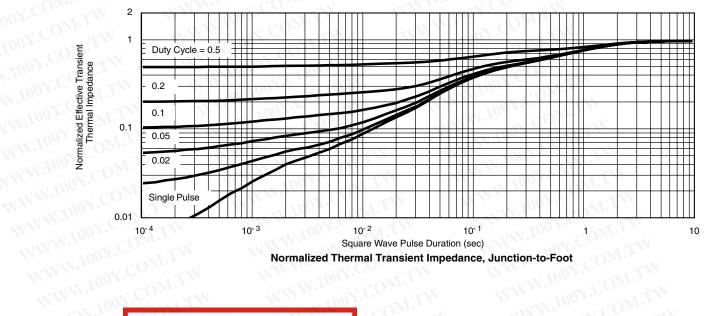
Safe Operating Area, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Ambient



#### TYPICAL CHARACTERISTICS 25 °C unless noted



Normalized Thermal Transient Impedance, Junction-to-Foot WWW.100Y.COM.TW

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